A general theory of learning and memory with Complex Synapses

based on work with Surya Ganguli

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April 9, 2013

Complex synapses

general theory of learning and memory with Complex Synapses

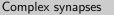
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Introduction

We often model synaptic plasticity as the change of a single number (synaptic weight). In reality, there is a complex dynamical system inside a synapse.

Semi-realistic models of synaptic memory have terrible storage without synaptic complexity.

We will study the entire space of a broad class of models of complex synapses to find upper bounds on their performance.



2013-04-09

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We will study the entire space of a broad class of models of complex synapses to find upper bounds on their performance.

- 1. amplitude of psp.
- 2. finite number of values.

Outline

- Why complex synapses?
- 2 Modelling synaptic complexity
- 3 Upper bounds
- 4 Envelope memory curve

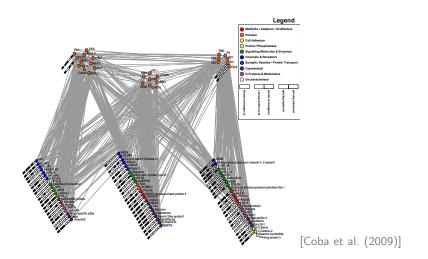


- 1. review terrible properties of simple synapses.
- 2. mathematical formalism of model, quantify performance (memory decay over time)
- 3. upper bounds on single numbers that describe performance at all times
- 4. upper bounds at finite times

Section 1

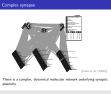
Why complex synapses?

Complex synapse



There is a complex, dynamical molecular network underlying synaptic plasticity.

Complex synapses —Why complex synapses?



- 1. Does this matter?
- 2. Could just be the machinery for changing synaptic weight
- 3. link back to questions on "There"

-Complex synapse

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Storage capacity of synaptic memory

A classical perceptron (used as a recognition memory device) has a capacity $\propto N$, the number of synapses.

Requires synapses' dynamic range also $\propto N$.

If we restrict synaptic weight to a fixed, finite set of values,

⇒ tradeoff between learning and forgetting: new memories overwriting old.

If we wish to store new memories rapidly, memory capacity $\sim \mathcal{O}(\log N)$.

[Amit and Fusi (1992), Amit and Fusi (1994)]

To circumvent this tradeoff, need to go beyond model of a synapse as a single number.



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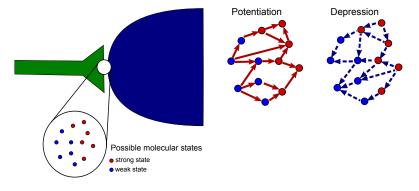
Complex synapses -Modelling synaptic complexity

Section 2 Modelling synaptic complexity

Section 2

Modelling synaptic complexity

Complex synapses



Complex synapses

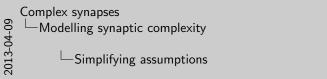
Modelling synaptic complexity

Complex synapses



Simplifying assumptions

- There are N identical synapses with M internal functional states.
- States of different synapses are independent of each other.
- Which synapses eligible for plasticity chosen randomly.
- Potentiating/depressing plasticity events \sim Poisson processes with rates $rf^{\text{pot/dep}}$, where $f^{\text{pot}} + f^{\text{dep}} = 1$.
- Potentiation and depression are described by Markov processes with transition probabilities M^{pot/dep}.
- Synaptic weights of the internal states are given by vector \mathbf{w} . Can only take values ± 1 .





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In other words, r is the total rate of plasticity events per synapse and $f^{\text{pot/dep}}$ are the fraction of these events that are potentiating/depressing.

Probabilities

At t = 0, the memory is created by $\mathbf{M}^{\text{pot/dep}}$ with probability $f^{\text{pot/dep}}$.

Forgetting caused by subsequent memories, evolving as

$$\frac{\mathrm{d}\mathbf{p}(t)}{\mathrm{d}t} = r\mathbf{p}(t)\mathbf{W}^{\mathrm{F}}, \qquad \mathbf{W}^{\mathrm{F}} = f^{\mathrm{pot}}\mathbf{M}^{\mathrm{pot}} + f^{\mathrm{dep}}\mathbf{M}^{\mathrm{dep}} - \mathbf{I},$$

Eventually, this will settle into the equilibrium distribution:

$$\mathbf{p}^{\infty}\mathbf{W}^{\mathrm{F}}=0.$$



Complex synapses Modelling synaptic complexity

└─ Probabilities

- 1. for this one, we keep track of pot/dep
- 2. W^F is forgetting matrix, don't keep track of pot/dep
- 3. In equilibrium prior to memory creation

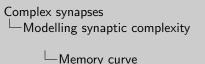
Memory curve

 \vec{w} is the *N*-element vector of synaptic weights.

$$\mathsf{Signal} = \langle ec{w}_\mathsf{ideal} \cdot ec{w}(t) - ec{w}_\mathsf{ideal} \cdot ec{w}(\infty)
angle$$
 $\mathsf{Noise} = \mathsf{Var} \left(ec{w}_\mathsf{ideal} \cdot ec{w}(\infty) \right)$

Related to reconstruction probability of single synapses.

$$\mathsf{SNR}(t) \sim \sqrt{N} \, P(\mathsf{strong/weak}, t | \mathsf{pot/dep}, t = 0) - \dots (t = \infty).$$

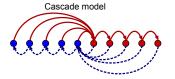


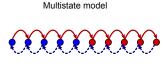


- 1. of different synapses
- 2. ideal: pot→strong...
- 3. if we ignore correlations...

Example models

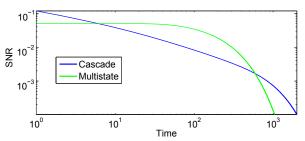
Two example models of complex synapses.





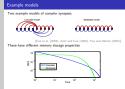
[Fusi et al. (2005), Amit and Fusi (1994), Fusi and Abbott (2007)]

These have different memory storage properties



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-Example models



Questions

- Can we understand the space of all possible synaptic models?
- How does structure (topology) of model → function (memory curve)?
- What are the limits on what can be achieved?
- Which transition topologies saturate these limits?



- 1. not just individual models
- 2. understand net (link on topology)
- 3. avoid using word "optimal". depends on what want to do.

Memory curve 2

Memory curve given by

$$\mathsf{SNR}(t) = rac{\sqrt{N}(2f^\mathsf{pot}f^\mathsf{dep})}{\sqrt{oldsymbol{p}_+^\inftyoldsymbol{p}_-^\infty}}\, oldsymbol{\mathsf{p}}^\infty \left(oldsymbol{\mathsf{M}}^\mathsf{pot} - oldsymbol{\mathsf{M}}^\mathsf{dep}
ight) \mathsf{exp}\left(\mathit{rt}oldsymbol{\mathsf{W}}^\mathrm{F}
ight) oldsymbol{\mathsf{w}}.$$

Constraints:

$$\mathbf{M}_{ij}^{ extsf{pot/dep}} \in [0,1], \qquad \sum_{i} \mathbf{M}_{ij}^{ extsf{pot/dep}} = 1.$$

Eigenmode decomposition:

$$\mathsf{SNR}(t) = \sqrt{N} \sum_{a} \mathcal{I}_a \, \mathsf{e}^{-rt/ au_a}.$$

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└─Memory curve 2



Memory curve 2

- 1. prefactors don't do anything, ignore
- 2. prior state, encoding, forgetting, readout
- 3. difficult to to apply
- 4. what are constraints on these?

Section 3

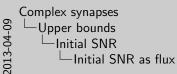
Upper bounds

Initial SNR as flux

Initial SNR is closely related to flux between strong & weak states

$$\mathsf{SNR}(0) \leq \frac{4\sqrt{N}}{r}\,\mathbf{\Phi}_{-+}.$$

Max when potentiation guarantees $\mathbf{w} \to +1$, depression guarantees $\mathbf{w} \to -1$.



1. usually saturated: pot never dec, dep never inc

Complex synapses Envelope memory curve

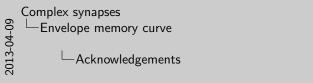
Section 4

Envelope memory curve

Acknowledgements

Thanks to:

- Surya Ganguli
- Stefano Fusi
- Marcus Benna



Acknowledgements

Thanks to:

- Surpa Canguli

- Stefano Fusi

- Marcus Benna

1. Last slide!

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Envelope memory curve

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